TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT153P,TC74ACT153F,TC74ACT153FN

Dual 4-Channel Multiplexer

The TC74ACT153 is an advanced high speed CMOS DUAL 4-CHANNEL MULTIPLEXERs fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipations.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

Each of these data (1C0-1C3, 2C0-2C3) is selected by the two address inputs A and B.

Separate strobe inputs $(1\overline{G}\;,\;\;2\overline{G}\;)$ are provided for each of the two four-line sections.

The strobe input can be used to inhibit the data output; the output is fixed in low level unconditionally.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 5.4 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A \text{ (max)}$ at $T_a = 25^{\circ}C$
- Compatible with TTL outputs: V_{IL} = 0.8 V (max)

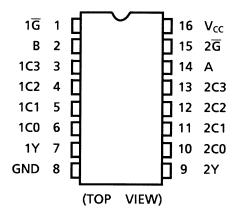
 $V_{IH} = 2.0 \text{ V (min)}$

 Symmetrical output impedance: | I_OH | = I_OL = 24 mA (min) Capability of driving 50 Ω

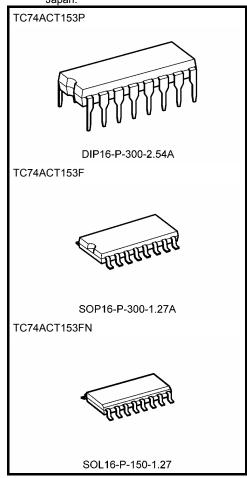
transmission lines.

- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F153

Pin Assignment



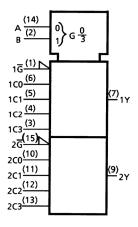
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.)

IEC Logic Symbol

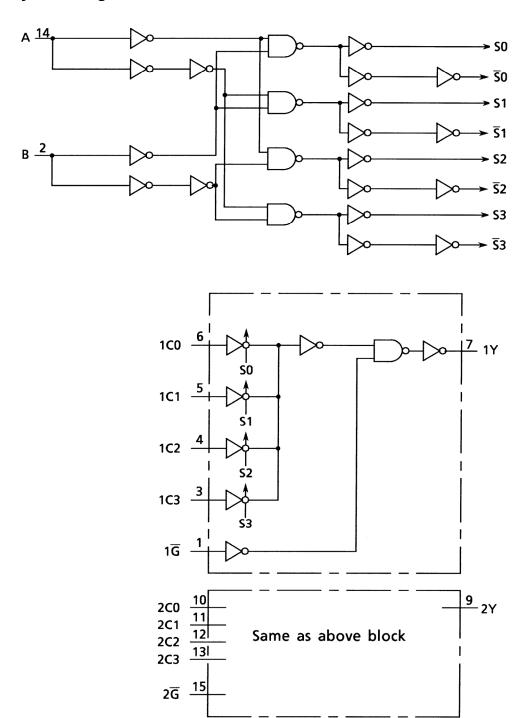


Truth Table

Select	Select Inputs		Data	Inputs	Strobe	Output		
В	Α	CO	C1	C2	C3	IG	Υ	
Х	Х	Х	Х	Х	Х	Н	L	
L	L	L	Х	Х	Х	L	L	
L	L	Н	Х	Х	Х	L	Н	
L	Н	Х	L	Х	Х	L	L	
L	Н	Х	Н	Х	Х	L	Н	
Н	L	Х	Х	L	Х	L	L	
Н	L	Х	Х	Н	Х	L	Н	
Н	Н	Х	Х	Х	L	L	L	
Н	Н	Х	Х	Х	Н	L	Н	

X: Don't care

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	−0.5 to V _{CC} + 0.5	٧
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	T _{opr}	−40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		- Unit	
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
High-level input voltage	V _{IH}	_			4.5 to 5.5	2.0	_	_	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	_	0.8	_	0.8	V	
	Voн	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$		4.5	4.4	4.5	_	4.4	_	
High-level output voltage			$I_{OH} = -24 \text{ mA}$		4.5	3.94	_	_	3.80	_	V
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	_	_	3.85	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I _{OL} = 24 mA		4.5	_	_	0.36	_	0.44	V
			$I_{OL} = 75 \text{ mA}$	(Note)	5.5	_	_	_	_	1.65	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND			5.5	_	_	±0.1	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	8.0	_	80.0	μА	
	Ic	Per input: V _{IN} = 3.4 V		5.5	_	_	1.35	_	1.5	mA	
		Other input: V _{CC} or GND									

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (CL = 50 pF, RL = 500 Ω , input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay time (Cn-Y)	t _{pLH}	_	5.0 ± 0.5	_	6.1	9.7	1.0	11.0	ns
Propagation delay time (A, B-Y)	t _{pLH}	_	5.0 ± 0.5	_	7.8	11.8	1.0	13.5	ns
Propagation delay time (\overline{G} -Y)	t _{pLH}	_	5.0 ± 0.5	_	5.6	9.7	1.0	11.0	ns
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)			_	47	_	_	_	pF

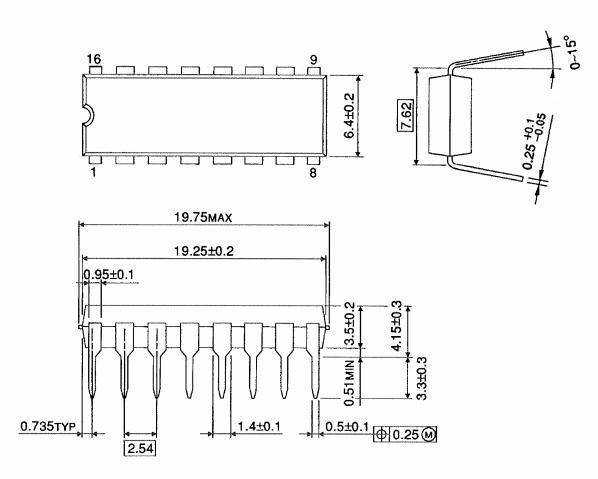
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

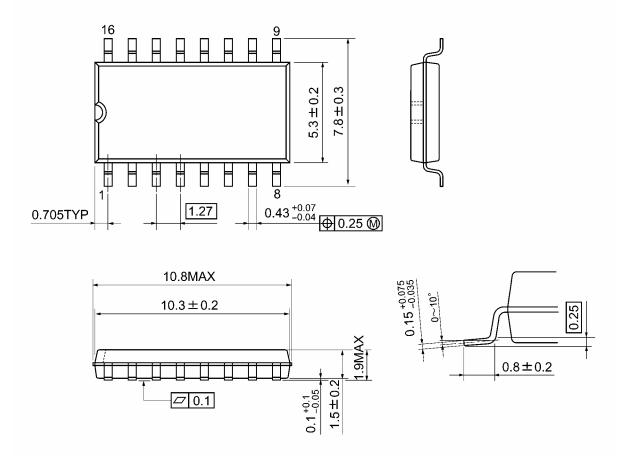
DIP16-P-300-2.54A Unit: mm



Weight: 1.00 g (typ.)

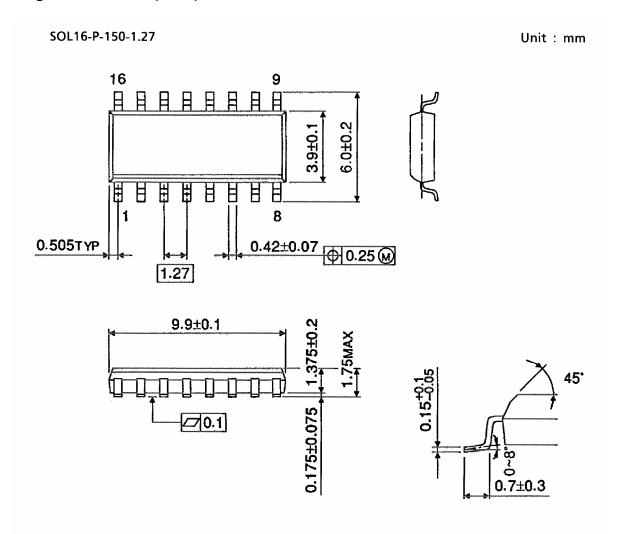
Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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